

# HiPerFRED

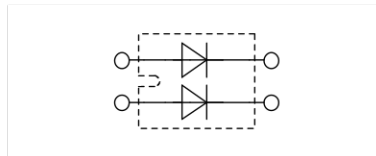
High Performance Fast Recovery Diode

Low Loss and Soft Recovery

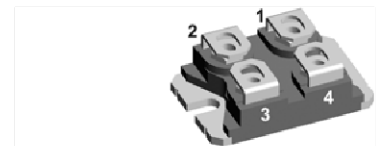
Parallel legs

Part number

DSEP2x61-06A



$$\begin{aligned} V_{RRM} &= 600 \text{ V} \\ I_{FAV} &= 2 \times 60 \text{ A} \\ t_{rr} &= 35 \text{ ns} \end{aligned}$$



Backside: isolated

## Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{RM}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{RM}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

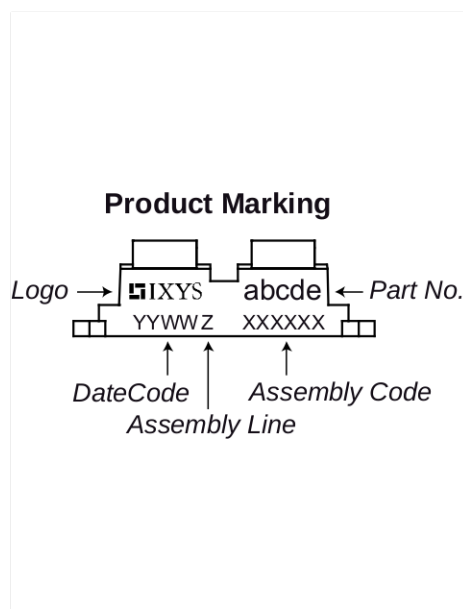
## Package:

- Housing: SOT-227B (minibloc)
- Industry standard outline
- Cu base plate internal DCB isolated
- Isolation Voltage 3000 V
- Epoxy meets UL 94V-0
- RoHS compliant

E72873

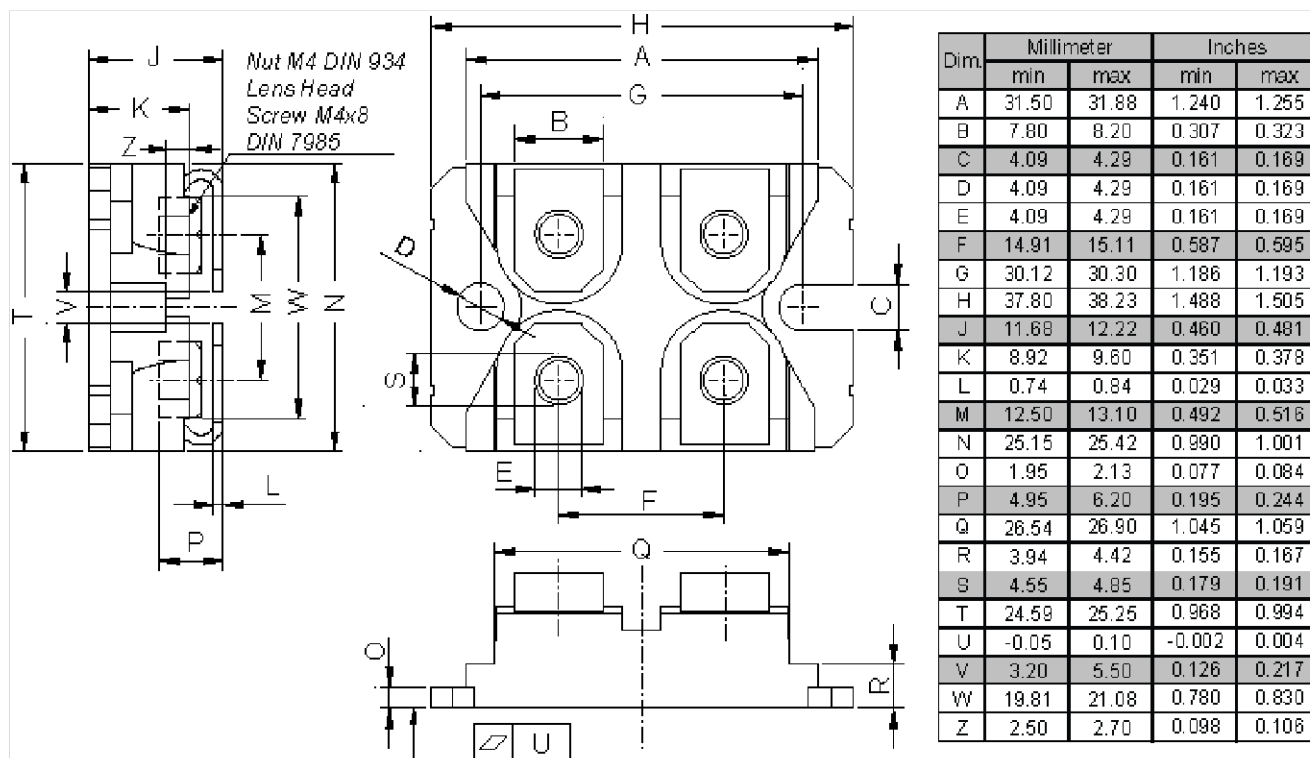
| Symbol     | Definition                          | Conditions                                |                                | Ratings |      |      |                    |
|------------|-------------------------------------|-------------------------------------------|--------------------------------|---------|------|------|--------------------|
|            |                                     |                                           |                                | min.    | typ. | max. | Unit               |
| $V_{RRM}$  | max. repetitive reverse voltage     |                                           | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 600  | V                  |
| $I_R$      | reverse current                     | $V_R = 600 \text{ V}$                     | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 650  | $\mu\text{A}$      |
|            |                                     | $V_R = 600 \text{ V}$                     | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 2.5  | mA                 |
| $V_F$      | forward voltage                     | $I_F = 60 \text{ A}$                      | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 2.01 | V                  |
|            |                                     | $I_F = 120 \text{ A}$                     |                                |         |      | 2.27 | V                  |
|            |                                     | $I_F = 60 \text{ A}$                      | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 1.35 | V                  |
|            |                                     | $I_F = 120 \text{ A}$                     |                                |         |      | 1.63 | V                  |
| $I_{FAV}$  | average forward current             | rectangular $d = 0.5$                     | $T_C = 65^{\circ}\text{C}$     |         |      | 60   | A                  |
| $V_{F0}$   | threshold voltage                   | } for power loss calculation only         | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 1.09 | V                  |
| $r_F$      | slope resistance                    |                                           |                                |         |      | 4.3  | m $\Omega$         |
| $R_{thJC}$ | thermal resistance junction to case |                                           |                                |         |      | 0.85 | K/W                |
| $T_{VJ}$   | virtual junction temperature        |                                           |                                | -40     |      | 150  | $^{\circ}\text{C}$ |
| $P_{tot}$  | total power dissipation             |                                           | $T_C = 25^{\circ}\text{C}$     |         |      | 140  | W                  |
| $I_{FSM}$  | max. forward surge current          | $t = 10 \text{ ms}$ (50 Hz), sine         | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 600  | A                  |
| $I_{RM}$   | max. reverse recovery current       |                                           | $T_{VJ} = 25^{\circ}\text{C}$  |         | 18   |      | A                  |
|            |                                     | $I_F = 60 \text{ A}; V_R = 300 \text{ V}$ | $T_{VJ} = 100^{\circ}\text{C}$ |         | 30   |      | A                  |
|            |                                     | $-di_F/dt = 600 \text{ A}/\mu\text{s}$    | $T_{VJ} = 25^{\circ}\text{C}$  |         | 30   |      | ns                 |
|            |                                     |                                           | $T_{VJ} = 100^{\circ}\text{C}$ |         | 55   |      | ns                 |
| $C_J$      | junction capacitance                | $V_R = 400 \text{ V}; f = 1 \text{ MHz}$  | $T_{VJ} = 25^{\circ}\text{C}$  |         | 67   |      | pF                 |

| Symbol        | Definition                                            | Conditions           | Ratings |      |      | Unit |
|---------------|-------------------------------------------------------|----------------------|---------|------|------|------|
|               |                                                       |                      | min.    | typ. | max. |      |
| $I_{RMS}$     | RMS current                                           | per terminal         |         |      | 100  | A    |
| $R_{thCH}$    | thermal resistance case to heatsink                   |                      |         | 0.10 |      | K/W  |
| $T_{stg}$     | storage temperature                                   |                      | -40     |      | 150  | °C   |
| Weight        |                                                       |                      |         | 30   |      | g    |
| $M_D$         | mounting torque                                       |                      | 1.1     |      | 1.5  | Nm   |
| $M_T$         | terminal torque                                       |                      | 1.1     |      | 1.5  | Nm   |
| $V_{ISOL}$    | isolation voltage                                     | t = 1 second         | 3000    |      |      | V    |
|               |                                                       | t = 1 minute         | 2500    |      |      | V    |
| $d_{Spp/App}$ | creepage   striking distance on surface   through air | terminal to terminal | 10.5    | 3.2  |      | mm   |
| $d_{Spb/Apb}$ | creepage   striking distance on surface   through air | terminal to backside | 8.6     | 6.8  |      | mm   |



| Ordering | Part Name    | Marking on Product | Delivering Mode | Base Qty | Code Key |
|----------|--------------|--------------------|-----------------|----------|----------|
| Standard | DSEP2x61-06A | DSEP2x61-06A       | Tube            | 10       | 474754   |

## Outlines SOT-227B (minibloc)



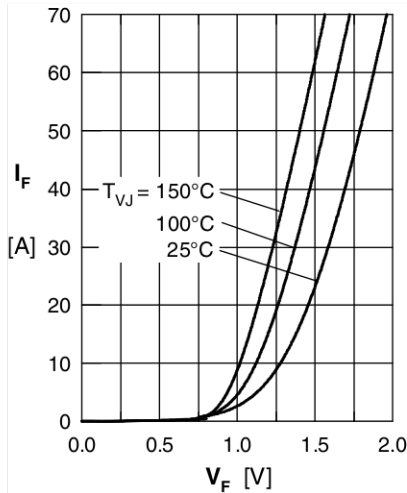


Fig. 1 Forward current  $I_F$  vs.  $V_F$

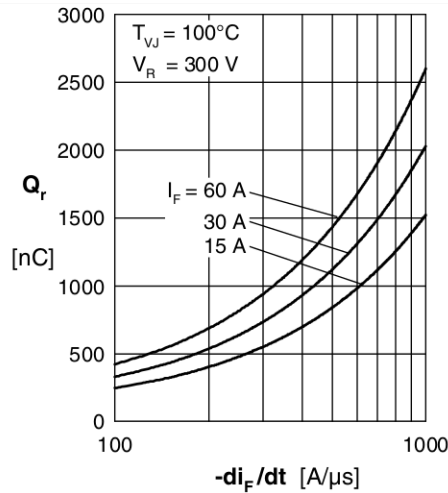


Fig. 2 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$

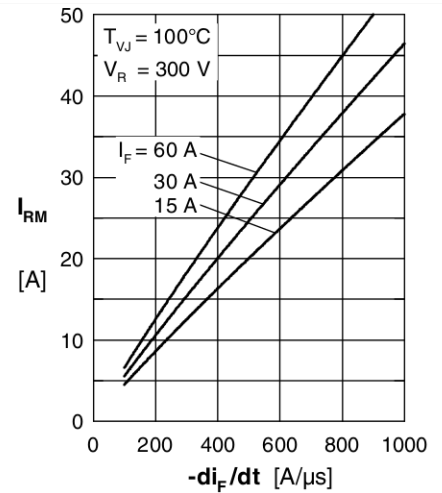


Fig. 3 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$

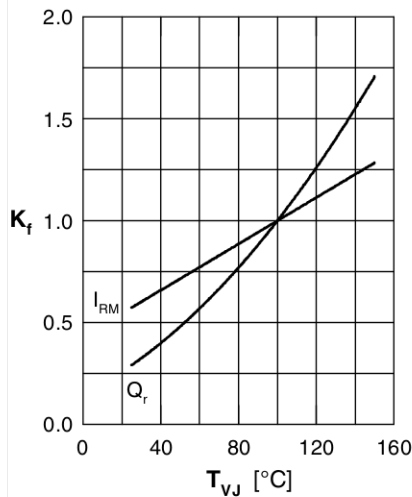


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

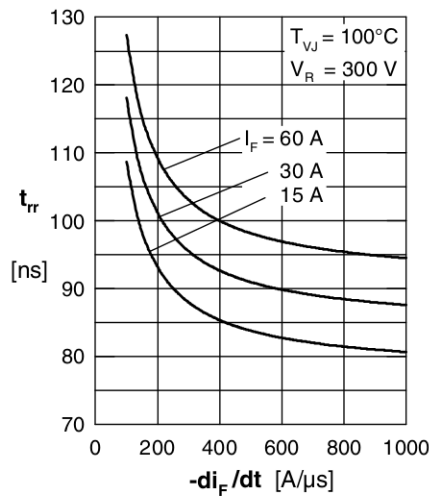


Fig. 5 Recovery time  $t_{rr}$  versus  $-di_F/dt$

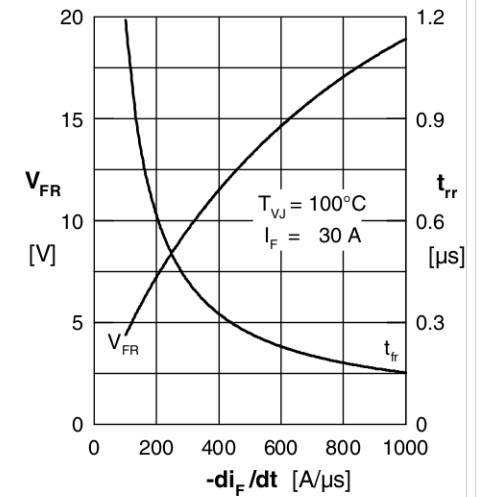


Fig. 6 Peak forward voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$

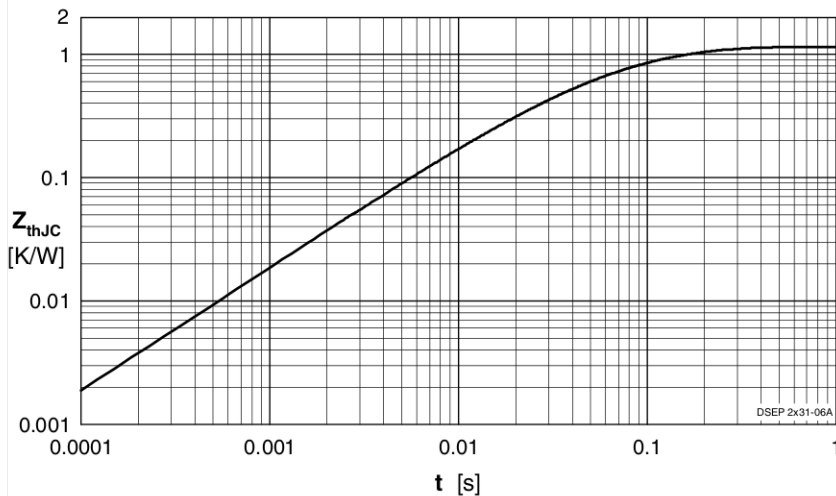


Fig. 7 Transient thermal resistance junction to case

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.436           | 0.0055    |
| 2 | 0.482           | 0.0092    |
| 3 | 0.117           | 0.0007    |
| 4 | 0.115           | 0.0418    |